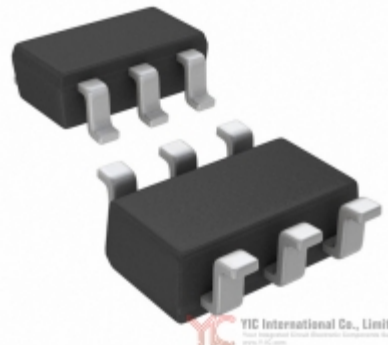







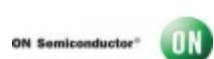

	<h2 style="color: red;">NVGS4111PT1G</h2>	
	Hersteller-Teilenummer:	NVGS4111PT1G
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	MOSFET P-CH 30V 3.7A 6TSOP
Datenblätter:	 NVGS4111PT1G.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 3000 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	NVGS4111PT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET P-CH 30V 3.7A 6TSOP
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	3000 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-23-6
Supplier Device-Gehäuse	6-TSOP
Verlustleistung (max)	630mW (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	3.7A (Ta)
Rds On (Max) @ Id, Vgs	60 mOhm @ 3.7A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	32nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	750pF @ 15V
Verpackung	Tape & Reel (TR)

NVGS4111PT1G ist neu im Original, Suche NVGS4111PT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NVGS4111PT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NVGS4111PT1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NVGS3130NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 20V 4.2A 6TSOP</p>	 <p>NVGS3136PT1G ON NVGS3136PT1G ON</p>	 <p>NVGS4141NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 3.5A 6TSOP</p>	 <p>NVGS5120PT1G AMI Semiconductor / ON Semiconductor MOSFET P-CH 60V 1.8A 6TSOP</p>
 <p>NVGS3443T1G AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 2A 6-TSOP</p>	 <p>TSM8N80CI C0G TSC (Taiwan Semiconductor) MOSFET N-CHANNEL 800V 8A ITO220</p>	 <p>NVGS3130N AMI Semiconductor / ON Semiconductor NVGS3130N ON</p>	 <p>NVGS3441T1G AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 2.35A 6-TSOP</p>

heiße Teile

Mehr

08051C471JAT2A	24LC512T-I/SN	2FI50F-030	ADF4113BRU-REEL7	BAW156-7-F
BCX56-10E6327	BD3539FVM-RTR	BZB84-B5V6/DG	C1005X8R1H682M050BE	CC1206FRNPO9BN332
CGA1A2C0G1H6R8D030BA	CGA3EAC0G2A332J080AC	CGJ4J2X7R1A475K125AA	DS24B33S+	FAN54046UCX
GRM0335C1E2R1BA01D	GRM0335C1E3R8BA01D	GRM1557U1A222JA01D	GRT155R61E474KE01D	ISL6522CB2-TR5190
ISL97670IRZ-TR5497	LE75181ABSC	LM4860MX/NOPB	MA2SV090Q1TD	MAX5742AUB-T
MAX7381AXR106+T	MAX8213AEJE	MC705B16NCFUE	NVGS3130N	NVGS3130NT1G
NVGS3136PT1G	D NVGS3441T1G	NVGS3443T1G	NVGS4141NT1G	NVGS5120PT1G
PXFT15BG103QA1B050	QT1106-ISG	R1446NS12E	S25FL004AOLMAI001	SMAJ40CA-E3/61
SSA24L-E3/5AT	STN2N10L	STP16N65M5	TC518128CFL-80	TL431AICT
TNY268GN-TL	UC3852DTRG4	VAAH211	VI-20-EX	WSL2512R2200FEA

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